

View Online at <https://aerobasegroup.com/nsn/5961-00-465-9871>

Inclosure Material:

Metal

Overall Length:

0.440 inches

Overall Diameter:

0.260 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Press fit

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open all transistor and 15.0 breakdown voltage, collector-to-emitter, base open all transistor and 4.5 emitter to base voltage, static, collector open all transistor

Current Rating Per Characteristic:

100.00 milliamperes source cutoff current all transistor

Power Rating Per Characteristic:

1400.0 milliwatts small-signal input power, common-collector preset all transistor

Transfer Ratio:

120.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

All transistor junction pattern arrangement: npn

Terminal Type And Quantity:

6 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

A110a0